Memory Microcircuit - Page 1 of 1

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# Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Next assembly: 8506200-91

#### **Features Provided:**

Programmed and tested to mil-std-883

## Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

### Case Outline Source And Designator:

C-4 mil-m-38510

**Product Name:** 

2k x 8 registered prom

#### Voltage Rating And Type Per Characteristic:

4.5 volts applied and 5.5 volts applied

Memory Device Type:

Prom

Hybrid Technology Type:

Monolithic

Special Features:

One time programmable

# **Test Data Document:**

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

28 leadless

**Specification Data:** 

67268-5962-88735033a government standard

#### **Departure From Cited Designator:**

Prograamed per: (07187)tt8514393-100

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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